

# RJK2508DPK

Silicon N Channel MOS FET  
High Speed Power Switching

REJ03G0508-0300

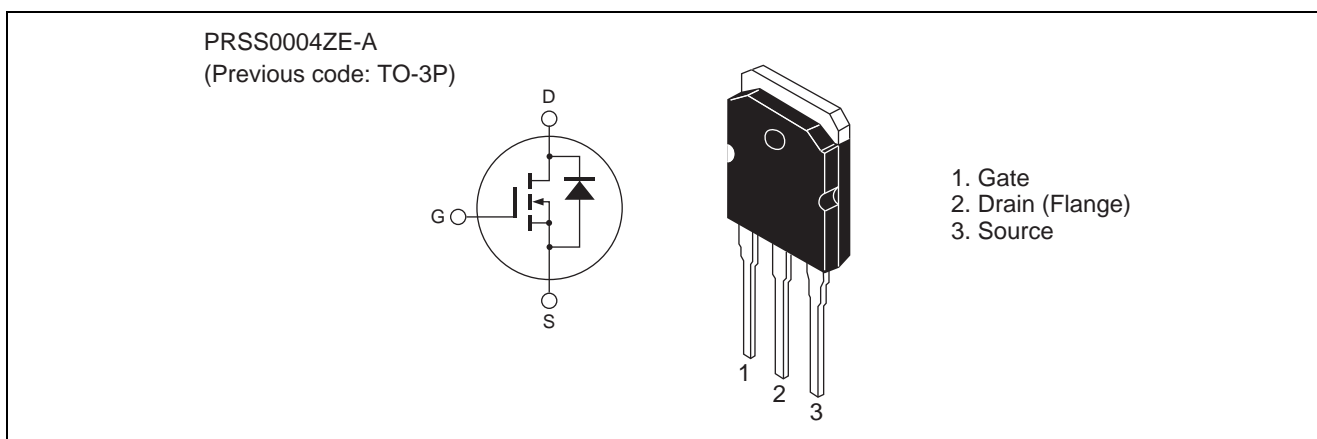
Rev.3.00

Jun 30, 2010

## Features

- Low on-resistance
- Low leakage current
- High speed switching

## Outline



## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to Source voltage	$V_{DS}$	250	V
Gate to Source voltage	$V_{GS}$	$\pm 30$	V
Drain current	$I_D$	50	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	100	A
Body-Drain diode reverse Drain current	$I_{DR}$	50	A
Body-Drain diode reverse Drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	100	A
Avalanche current	$I_{AP}$ <sup>Note3</sup>	17	A
Avalanche energy	$E_{AR}$ <sup>Note3</sup>	18.0	mJ
Channel dissipation	$P_{ch}$ <sup>Note2</sup>	150	W
Channel to case thermal impedance	$\theta_{ch-c}$	0.833	°C/W
Channel temperature	$T_{ch}$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Notes: 1.  $PW \leq 10 \mu s$ , duty cycle  $\leq 1\%$

2. Value at  $T_c = 25^\circ C$

3.  $STch = 25^\circ C$ ,  $T_{ch} \leq 150^\circ C$

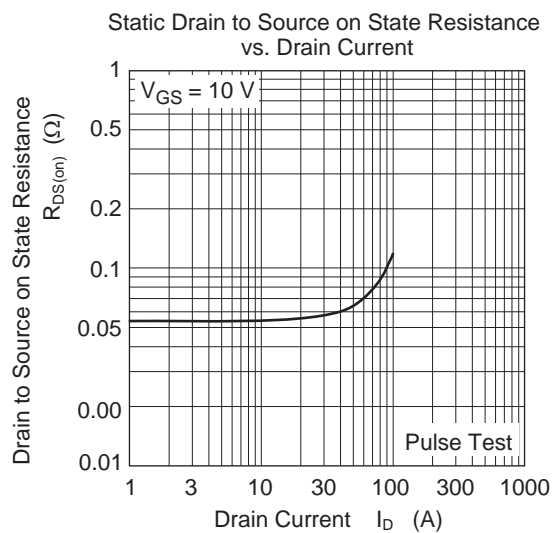
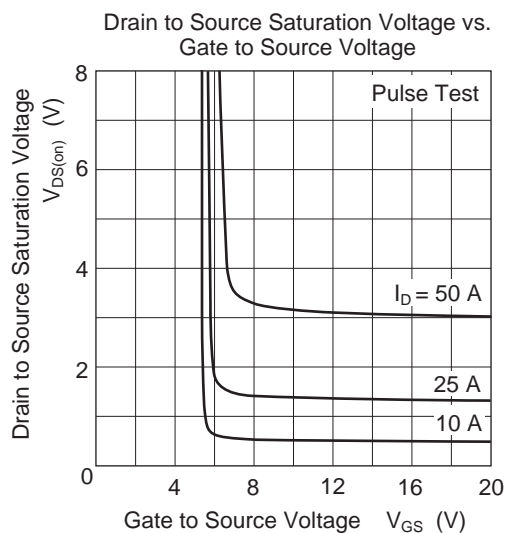
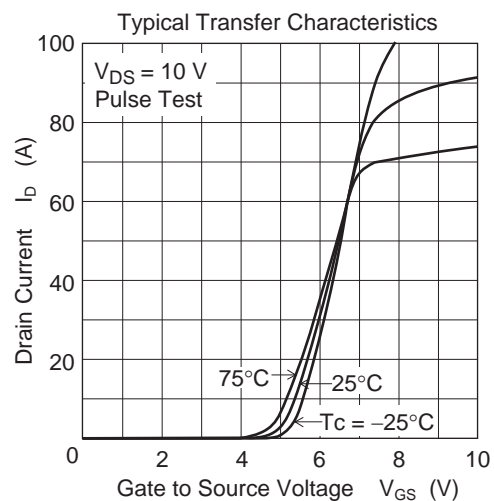
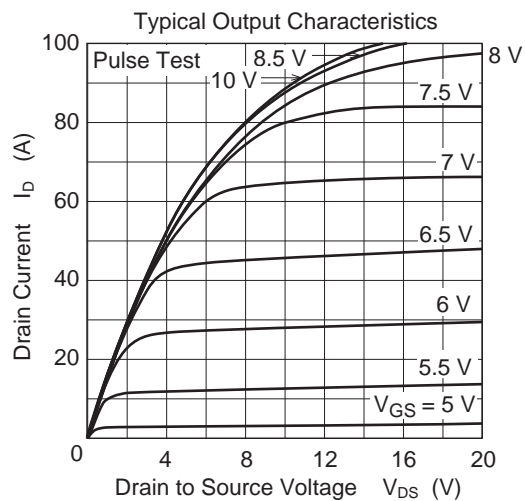
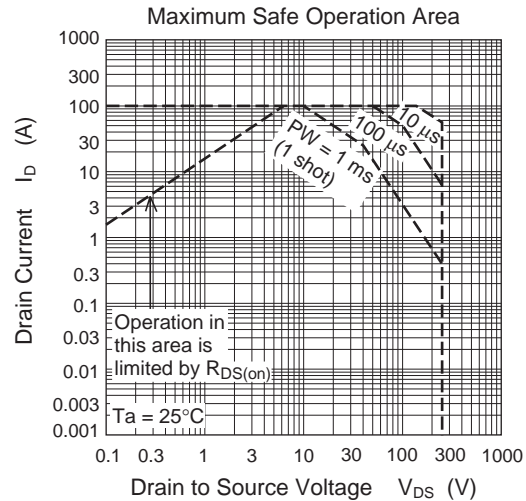
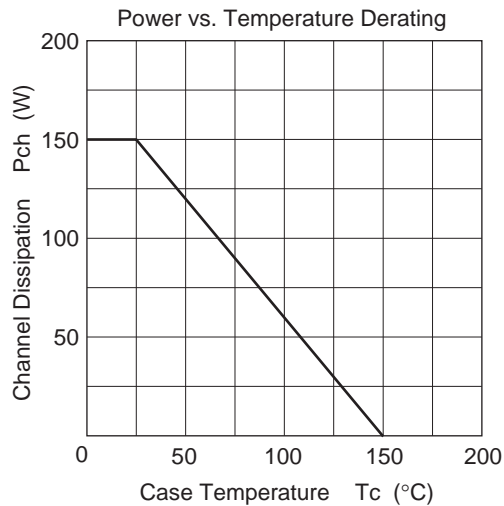
## Electrical Characteristics

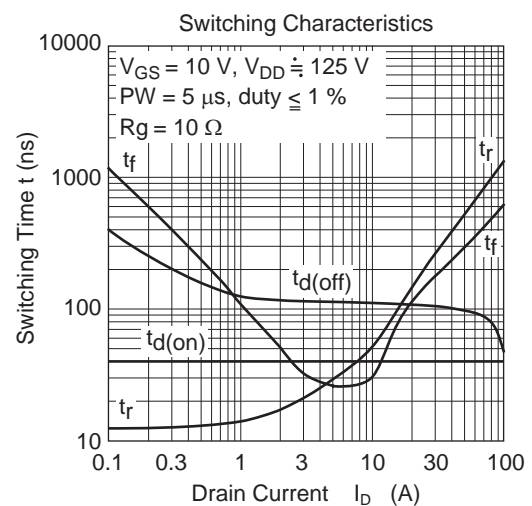
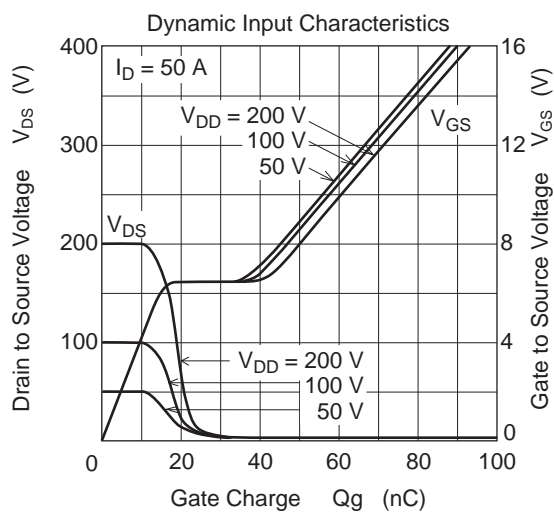
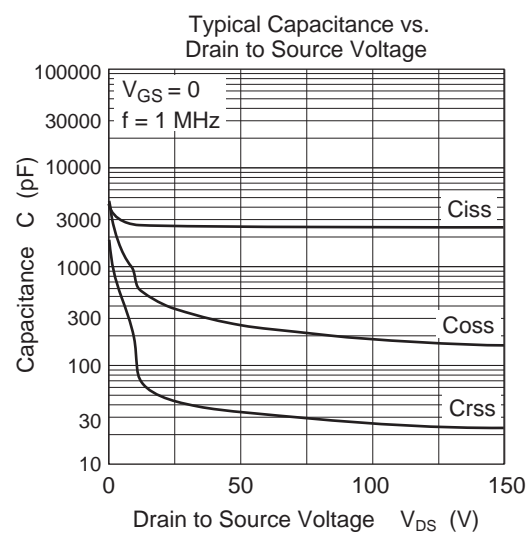
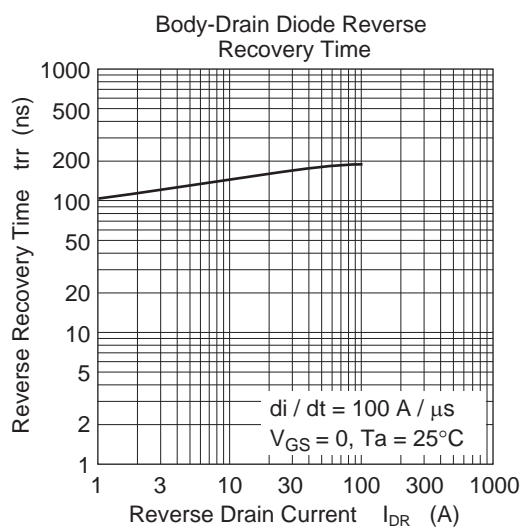
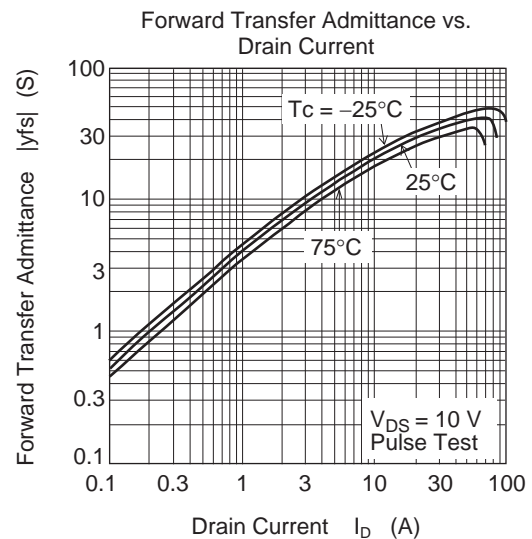
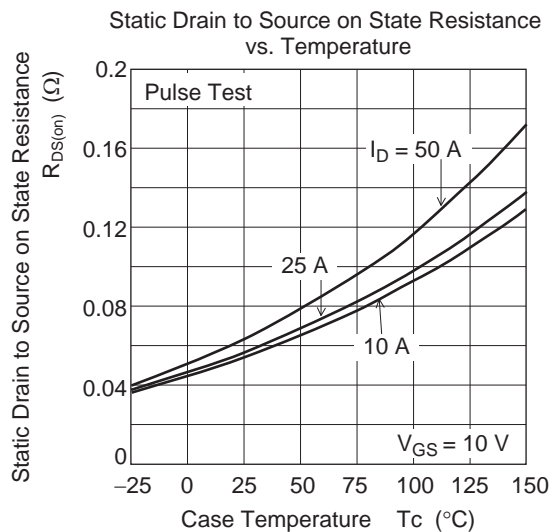
(Ta = 25°C)

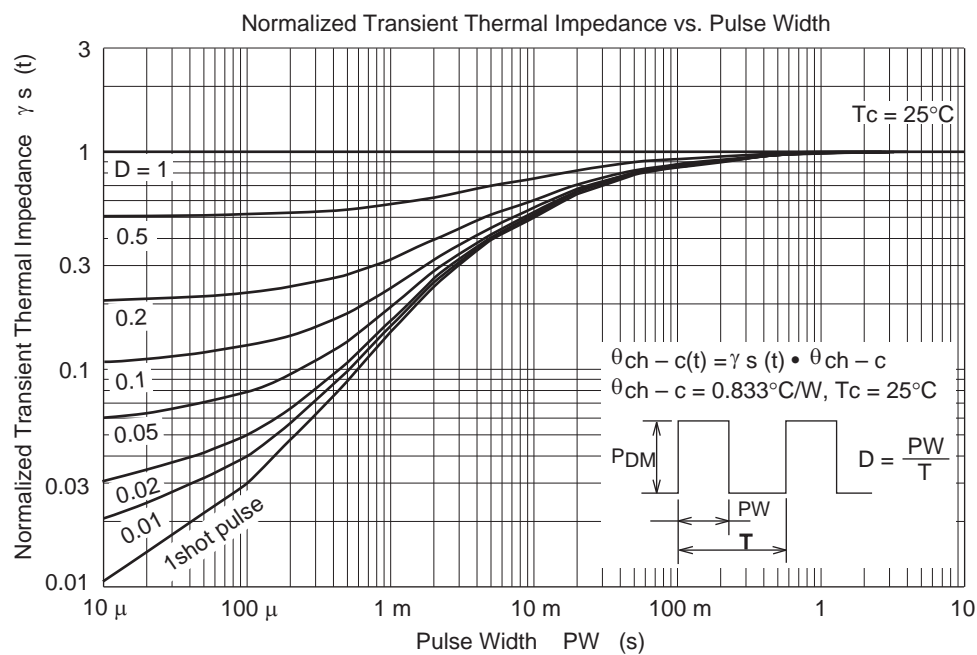
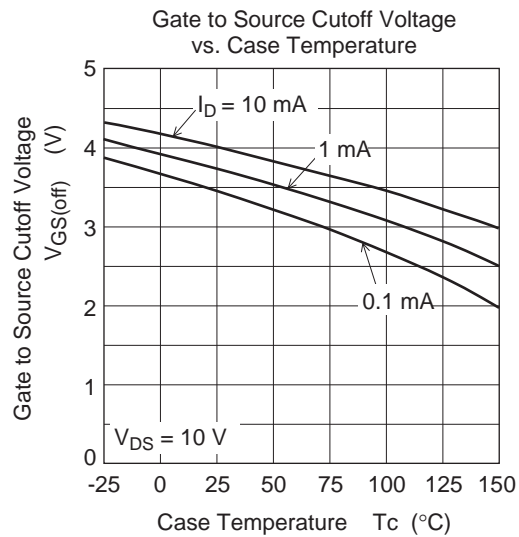
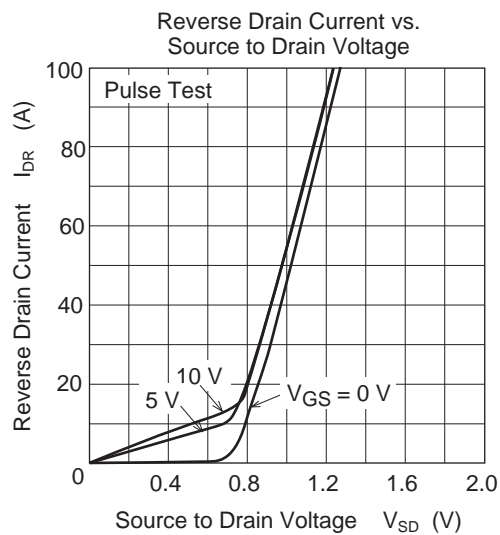
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	250	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Zero Gate voltage Drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 250 \text{ V}$ , $V_{GS} = 0$
Gate to Source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Forward transfer admittance	$ y_{fs} $	19	32	—	S	$I_D = 25 \text{ A}$ , $V_{DS} = 10 \text{ V}$ <sup>Note4</sup>
Static Drain to Source on state resistance	$R_{DS(on)}$	—	0.056	0.064	$\Omega$	$I_D = 25 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note4</sup>
Input capacitance	$C_{iss}$	—	2600	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	$C_{oss}$	—	370	—	pF	
Reverse transfer capacitance	$C_{rss}$	—	43	—	pF	
Turn-on delay time	$t_{d(on)}$	—	40	—	ns	$I_D = 25 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 5 \Omega$ $R_g = 10 \Omega$
Rise time	$t_r$	—	210	—	ns	
Turn-off delay time	$t_{d(off)}$	—	110	—	ns	
Fall time	$t_f$	—	145	—	ns	
Total Gate charge	$Q_g$	—	60	—	nC	$V_{DD} = 200 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 50 \text{ A}$
Gate to Source charge	$Q_{gs}$	—	15	—	nC	
Gate to Drain charge	$Q_{gd}$	—	26	—	nC	
Body-Drain diode forward voltage	$V_{DF}$	—	1.0	1.5	V	$I_F = 50 \text{ A}$ , $V_{GS} = 0$ <sup>Note4</sup>
Body-Drain diode reverse recovery time	$t_{rr}$	—	180	—	ns	$I_F = 50 \text{ A}$ , $V_{GS} = 0$ $diF/dt = 100 \text{ A}/\mu\text{s}$
Body-Drain diode reverse recovery charge	$Q_{rr}$	—	1.2	—	$\mu\text{C}$	

Notes: 4. Pulse test

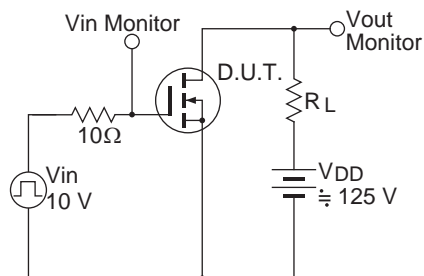
## Main Characteristics



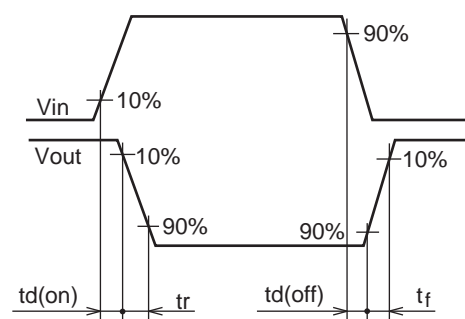




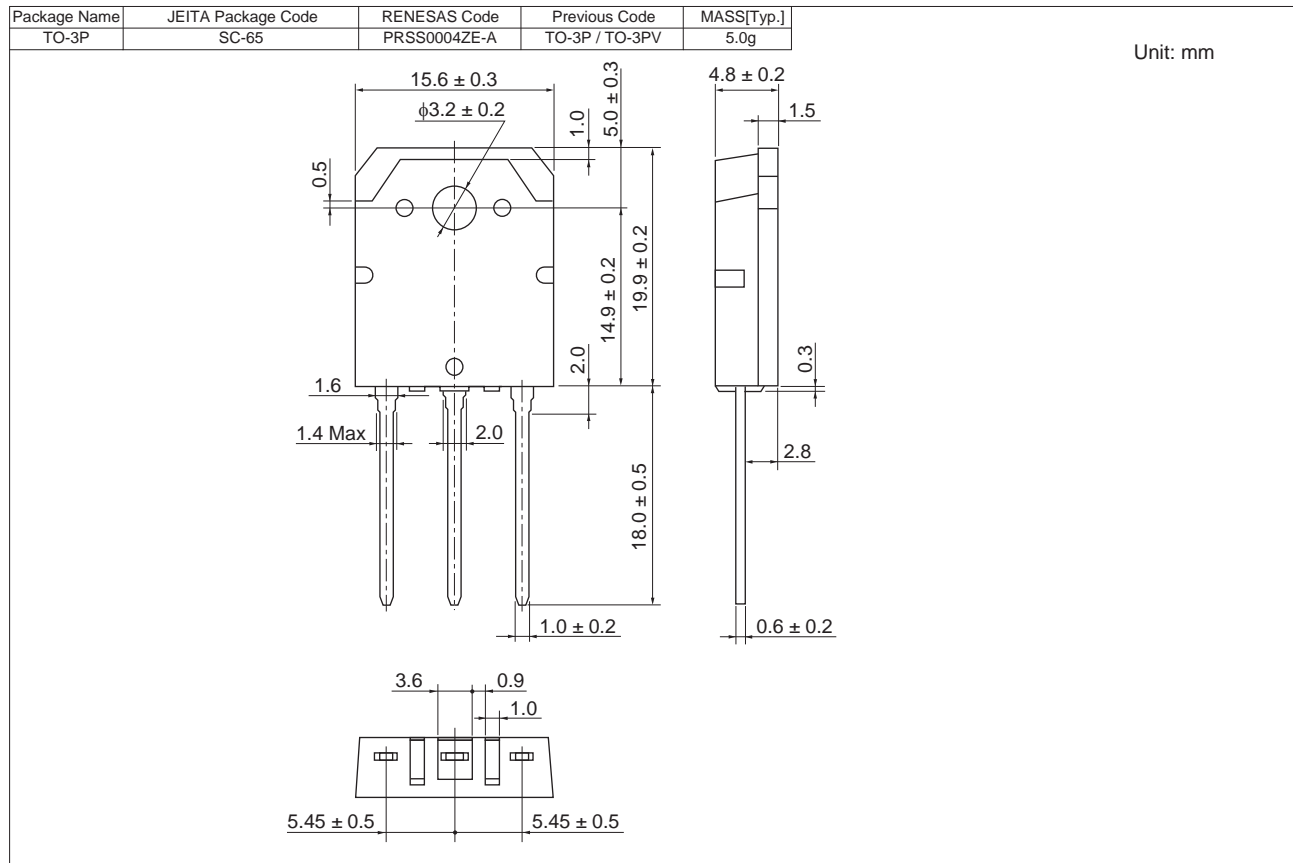
Switching Time Test Circuit



Waveform



## Package Dimensions



## Ordering Information

Part Name	Quantity	Shipping Container
RJK2508DPK-E	30 pcs	Plastic magazine

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